NSN 5961-01-064-9370

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-064-9370 **Inclosure Material:** Plastic **Overall Length:** 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-41 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5.1 regulator voltage **Current Rating Per Characteristic:** 178.00 milliamperes dc current in reverse breakdown region **Power Rating Per Characteristic:** 1.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No